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# Test & Measurement

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R&S AFQ100A I/Q Modulation Generator R&S AFQ100B UWB Signal and I/Q Modulation Generator Specifications

AFQ 100 B · UWB SIGNAL AND I/Q MODULATION GENERATOR

1410.9000K02 LNI

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HDE&SCHWARZ



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## Key features

# R&S<sup>®</sup>AFQ100A and R&S<sup>®</sup>AFQ100B specific features

### R&S<sup>®</sup>AFQ100A – fit for digital communications systems

- Variable memory clock rate (1 kHz to 300 MHz) can optimally be adjusted to the useful signal
- RF bandwidth of 200 MHz, e.g. for compensating higher-order non-linearities of multicarrier power amplifiers (MCPA)
- Long signal duration of up to 1 Gsample (R&S<sup>®</sup>AFQ-B11 option); long signals required e.g. for BER measurements
- R&S<sup>®</sup>WinIQSIM2<sup>™</sup> options for communications standards such as WiMAX, LTE, HSPA, etc.

#### R&S<sup>®</sup>AFQ100B – tailored to UWB applications

- Memory clock rate:
  - Mode 1: variable clock rate (1 kHz to 300 MHz) can optimally be adjusted to the useful signal
  - Mode 2: very high clock rate of 600 MHz
- RF bandwidth:
  - Mode 1: 200 MHz
  - Mode 2: 528 MHz (especially suited for UWB applications)
- Long signal duration of up to 1 Gsample (R&S<sup>®</sup>AFQ-B11 option). Long signals are required, for example, when using multisegment
  waveforms to reduce switching times between different test signals
- R&S<sup>®</sup>WinIQSIM2<sup>™</sup> option (R&S<sup>®</sup>AFQ-K264) for flexible UWB (EMCA-368) signal generation
- Nearly all R&S<sup>®</sup>AFQ100A features also included

# R&S<sup>®</sup>AFQ100A and R&S<sup>®</sup>AFQ100B shared features

#### Aerospace and defense applications

- · High bandwidth for generating very short pulses with short rise and fall times
- Pulse sequencer software for generating complex pulse patterns (R&S<sup>®</sup>AFQ-K6 option)
- Accuracy <20 ps when starting several instruments simultaneously → phased-array antenna development and testing
- · Removable hard disk to meet high security requirements

#### **Outstanding signal quality**

- Excellent spurious-free dynamic range (SFDR) of up to typ. 83 dBc
- Frequency response of typ. 0.05 dB across 100 MHz I/Q bandwidth
- Frequency response compensation
- Very pure sinewave source

#### Broad scope of applications

- Analog I/Q outputs (balanced and unbalanced) and optional digital outputs, e.g. for D/A and A/D converter tests
- · Multisegment waveform for reducing switching time between different test signals and thus improving test throughput
- Numerous trigger and marker capabilities, e.g. for synchronization with a DUT
- Optional BER measurements for characterizing receivers

#### Easy creation of test signals

- Digital standards using R&S<sup>®</sup>WinIQSIM2<sup>™</sup>
- Pulsed signals with pulse sequencer software (R&S®AFQ-K6 option)
- MATLAB<sup>®</sup> transfer toolbox for easy interoperability with MATLAB<sup>®</sup>
- ARB toolbox for converting numeric I/Q data into R&S®AFQ100A/R&S®AFQ100B waveform files

#### **Easy operation**

- Remote control via GPIB, USB and LAN
- User interface via external monitor or Windows XP Remote Desktop
- USB connectors for USB equipment (keyboard, mouse, memory stick)

# **Specifications**

#### **Output memory**

Memory clock of the R&S <sup>®</sup> AFQ100A		1 kHz to 300 MHz
Memory clock of the R&S <sup>®</sup> AFQ100B		1 kHz to 300 MHz (mode 1),
		600 MHz (mode 2)
Waveform length (data and markers) of		from 3 samples in steps of 1 sample
the R&S <sup>®</sup> AFQ100A	waveform memory (R&S <sup>®</sup> AFQ-B10)	up to 256 Msample
	waveform memory (R&S <sup>®</sup> AFQ-B11)	up to 1 Gsample
Waveform length (data and markers) of		from 3 samples in steps of 1 sample
the R&S <sup>®</sup> AFQ100B		(mode 1),
		from 6 samples in steps of 2 samples
		(mode 2)
	waveform memory (R&S <sup>®</sup> AFQ-B11)	up to 1 Gsample
	waveform memory (R&S <sup>®</sup> AFQ-B12)	up to 512 Msample
Waveform bandwidth		max. 0.33 × memory clock $^{1}$ ,
		max. 0.44 × memory clock <sup>2</sup>
Amplitude resolution of data words		16 bit analog and digital (R&S <sup>®</sup> AFQ-B18)
Marker channels		4
	control	
	by separate internal signal generators	pulse, pattern, ON/OFF ratio
	from main memory	4 bits per sample, deducted from
		waveform memory
	offset relative to signal waveform	0 samples to 2000 samples

### **Clock generation**

Clock rates, analog output	memory clock	1 kHz to 300 MHz <sup>1</sup>
		600 MHz <sup>2</sup>
	converter clock (with digital lowpass filter and clock rate converter)	1200 MHz
Clock rates, digital output, port 1 LVDS, multiplexed × 7)	interface clock (with digital lowpass filter and clock rate converter)	100 MHz
	data clock	700 MHz (in line with TIA644)
	memory clock	1 kHz to interface clock rate
	operating modes	
	with clock rate converter	with digital lowpass filter and clock rate conversion (memory clock to interface clock), configurable filter for frequency response correction
	with data enable	valid samples are marked with a "data valid" bit; system clock rate = memory clock
Clock rates, digital output, port 2	interface clock	1 kHz to 300 MHz
(LVDS, parallel)	data clock	same as interface clock (direct output, no filters)
	memory clock	same as interface clock
Resolution		$1 \times 10^{-7}$
Clock output		memory clock
	level	LVTTL, 2 V into 50 Ω
External clock input	input level	0 V to 3 V, threshold can be set betwee 10 mV and 1.9 V
	input impedance	50 Ω/1 kΩ, switchable
	frequency	1 kHz to 300 MHz

<sup>&</sup>lt;sup>1</sup> R&S<sup>®</sup>AFQ100A and R&S<sup>®</sup>AFQ100B, mode 1.

<sup>&</sup>lt;sup>2</sup> R&S<sup>®</sup>AFQ100B, mode 2.

### **Reference frequency**

Output for internal reference	frequency	10 MHz
	aging (after 30 days of operation)	1 × 10 <sup>-6</sup> /year
	temperature effect (+5 °C to +45 °C)	$1 \times 10^{-6}$
	level	$0.5 \text{ V} (\text{rms, sinewave, into } 50 \Omega)$
	output impedance	50 Ω
Input for external reference	frequency	10 MHz
	permissible frequency deviation	0.05 %
	level	0.2 V to 2 V (rms, sinewave)
	input impedance	50 Ω

### Signal output

	2 (I and Q)
	1 V ( $V_{pp}$ ) (into 50 $\Omega$ (nominal))
level range	0 V to 1.5 V (V <sub>pp</sub> ) (into 50 Ω)
•	0 dB to 21 dB in steps of 3 dB
fine variation	±5 %, separately for I and Q channel
	14 bit
	50 Ω each
	6 ns
	<pre>&lt;±1 % (at 1 kHz, after auto alignment)</pre>
	<pre>&lt;±0.1 % (at 1 kHz, after auto alignment)</pre>
	$\pm 0.05$ dB up to 50 MHz
	±0.1 dB up to 100 MHz
same as balanced outputs	if operated unbalanced, the other end
same as balanced outputs	should be terminated with 50 $\Omega$
	2 V (V <sub>DD</sub> )
	(between I and I into 100 $\Omega$ , nominal)
lovel range	$0 \text{ V to } 3 \text{ V } (\text{V}_{pp}) \text{ (into } 100 \Omega)$
	0  dB to 21 dB in steps of 3 dB
	±5 %, separately for I and Q channel
	14 bit
	50 $\Omega$ each
	-2.5 V to +2.5 V in steps of 10 mV
	6 ns
	<±1 % (at 1 kHz, after auto alignment)
level difference between the two channels	<±0.1 % (at 1 kHz, after auto alignment,
	bias voltage OFF)
	<±0.5 % (at 1 kHz, after auto alignment,
	bias voltage ON)
frequency response (relative to DC)	±0.05 dB up to 50 MHz
	±0.1 dB up to 100 MHz
	1 V (V <sub>pp</sub> ) (between I and $\overline{I}$ into 100 $\Omega,$
	nominal)
level range	0 V to 1.4 V (V <sub>pp</sub> ) (into 100 Ω)
hardware attenuator	0 dB, 6 dB
fine variation	±5 %, separately for I and Q channel
resolution	14 bit
impedance	50 Ω each
impedance	50 12 Eduli
bias voltage	-2.5 V to +2.5 V in steps of 10 mV
bias voltage	-2.5 V to +2.5 V in steps of 10 mV
bias voltage pulse rise/fall time (10 %/90 %)	<ul> <li>-2.5 V to +2.5 V in steps of 10 mV</li> <li>2.5 ns</li> <li>&lt;±1 % (at 1 kHz, after auto alignment)</li> </ul>
bias voltage pulse rise/fall time (10 %/90 %) level error (DC, at 1 V (V <sub>pp</sub> ))	<ul> <li>-2.5 V to +2.5 V in steps of 10 mV</li> <li>2.5 ns</li> <li>&lt;±1 % (at 1 kHz, after auto alignment)</li> <li>&lt;±0.1 % (at 1 kHz, after auto alignment,</li> </ul>
bias voltage pulse rise/fall time (10 %/90 %) level error (DC, at 1 V (V <sub>pp</sub> ))	<ul> <li>-2.5 V to +2.5 V in steps of 10 mV</li> <li>2.5 ns</li> <li>&lt;±1 % (at 1 kHz, after auto alignment)</li> <li>&lt;±0.1 % (at 1 kHz, after auto alignment, bias voltage OFF)</li> </ul>
bias voltage pulse rise/fall time (10 %/90 %) level error (DC, at 1 V (V <sub>pp</sub> ))	<ul> <li>-2.5 V to +2.5 V in steps of 10 mV</li> <li>2.5 ns</li> <li>&lt;±1 % (at 1 kHz, after auto alignment)</li> <li>&lt;±0.1 % (at 1 kHz, after auto alignment, bias voltage OFF)</li> <li>&lt;±0.5 % (at 1 kHz, after auto alignment,</li> </ul>
bias voltage pulse rise/fall time (10 %/90 %) level error (DC, at 1 V (V <sub>pp</sub> )) level difference between the two channels	<ul> <li>-2.5 V to +2.5 V in steps of 10 mV</li> <li>2.5 ns</li> <li>&lt;±1 % (at 1 kHz, after auto alignment)</li> <li>&lt;±0.1 % (at 1 kHz, after auto alignment, bias voltage OFF)</li> </ul>
bias voltage pulse rise/fall time (10 %/90 %) level error (DC, at 1 V (V <sub>pp</sub> ))	<ul> <li>-2.5 V to +2.5 V in steps of 10 mV</li> <li>2.5 ns</li> <li>&lt;±1 % (at 1 kHz, after auto alignment)</li> <li>&lt;±0.1 % (at 1 kHz, after auto alignment, bias voltage OFF)</li> <li>&lt;±0.5 % (at 1 kHz, after auto alignment, bias voltage ON)</li> <li>mode 1: ±0.5 dB up to 100 MHz,</li> </ul>
bias voltage pulse rise/fall time (10 %/90 %) level error (DC, at 1 V (V <sub>pp</sub> )) level difference between the two channels	<ul> <li>-2.5 V to +2.5 V in steps of 10 mV</li> <li>2.5 ns</li> <li>&lt;±1 % (at 1 kHz, after auto alignment)</li> <li>&lt;±0.1 % (at 1 kHz, after auto alignment, bias voltage OFF)</li> <li>&lt;±0.5 % (at 1 kHz, after auto alignment, bias voltage ON)</li> <li>mode 1: ±0.5 dB up to 100 MHz, typ. 0.3 dB</li> </ul>
bias voltage pulse rise/fall time (10 %/90 %) level error (DC, at 1 V (V <sub>pp</sub> )) level difference between the two channels	<ul> <li>-2.5 V to +2.5 V in steps of 10 mV</li> <li>2.5 ns</li> <li>&lt;±1 % (at 1 kHz, after auto alignment)</li> <li>&lt;±0.1 % (at 1 kHz, after auto alignment, bias voltage OFF)</li> <li>&lt;±0.5 % (at 1 kHz, after auto alignment, bias voltage ON)</li> <li>mode 1: ±0.5 dB up to 100 MHz, typ. 0.3 dB</li> <li>mode 2: ±0.8 dB up to 100 MHz,</li> </ul>
bias voltage pulse rise/fall time (10 %/90 %) level error (DC, at 1 V (V <sub>pp</sub> )) level difference between the two channels	<ul> <li>-2.5 V to +2.5 V in steps of 10 mV</li> <li>2.5 ns</li> <li>&lt;±1 % (at 1 kHz, after auto alignment)</li> <li>&lt;±0.1 % (at 1 kHz, after auto alignment, bias voltage OFF)</li> <li>&lt;±0.5 % (at 1 kHz, after auto alignment, bias voltage ON)</li> <li>mode 1: ±0.5 dB up to 100 MHz, typ. 0.3 dB</li> <li>mode 2: ±0.8 dB up to 100 MHz, typ. 0.5 dB</li> </ul>
bias voltage pulse rise/fall time (10 %/90 %) level error (DC, at 1 V (V <sub>pp</sub> )) level difference between the two channels	<ul> <li>-2.5 V to +2.5 V in steps of 10 mV</li> <li>2.5 ns</li> <li>&lt;±1 % (at 1 kHz, after auto alignment)</li> <li>&lt;±0.1 % (at 1 kHz, after auto alignment, bias voltage OFF)</li> <li>&lt;±0.5 % (at 1 kHz, after auto alignment, bias voltage ON)</li> <li>mode 1: ±0.5 dB up to 100 MHz, typ. 0.3 dB</li> <li>mode 2: ±0.8 dB up to 100 MHz,</li> </ul>
-	resolution         impedance         pulse rise/fall time (10 %/90 %)         level error (DC, at 1 V (V <sub>pp</sub> ))         level difference between the two channels         frequency response (relative to DC)         same as balanced outputs         level range         hardware attenuator         fine variation         resolution         impedance         bias voltage         pulse rise/fall time (10 %/90 %)         level difference between the two channels         frequency response (relative to DC)         level arge         hardware attenuator         fine variation         resolution         impedance         bias voltage         pulse rise/fall time (10 %/90 %)         level arge         hardware attenue between the two channels         frequency response (relative to DC)         level range         hardware attenuator         fine variation         resolution

Spectral purity of the R&S <sup>®</sup> AFQ100A	SFDR (without harmonics)	>80 dBc, typ. 83 dBc	
	harmonics		
	10 MHz signal	<-70 dBc, typ75 dBc	
	(bandwidth 0 Hz to 100 MHz,		
	$V_{out} = 1 V (V_{pp})$ , bias voltage OFF)		
	50 MHz signal	<-65 dBc, typ68 dBc	
	(bandwidth 0 Hz to 500 MHz,		
	$V_{out} = 1 V (V_{pp})$ , bias voltage OFF)		
	100 MHz signal	typ. –50 dBc	
	(bandwidth 0 Hz to 500 MHz,		
	$V_{out} = 1 V (V_{pp})$ , bias voltage OFF)		
	3GPP signal, test model 1/64		
	$(V_{out} = 1.5 V (V_{pp}))$ , bias voltage OFF) <sup>3</sup>		
	adjacent channel	typ. –80 dBc	
	alternate channel	typ. –80 dBc	
	3GPP signal, test model 1/64		
	$(V_{out} = 1.5 V (V_{pp}))$ , bias voltage OFF,		
	f(IF) = 25  MHz)		
	adjacent channel	typ. –75 dBc	
	alternate channel	typ. –77 dBc	
Spectral purity of the R&S <sup>®</sup> AFQ100B	SFDR (without harmonics)	>75 dBc, typ. 78 dBc	
	harmonics		
	1 MHz signal,	<-70 dBc, typ75 dBc	
	bandwidth 0 MHz to 100 MHz		
	$V_{out} = 0.5 V (V_{pp})$		
	10 MHz signal,	<-70 dBc, typ75 dBc	
	bandwidth 0 MHz to 100 MHz		
	$V_{out} = 0.5 V (V_{pp})$		
	50 MHz signal,	<-55 dBc, typ60 dBc	
	bandwidth 0 MHz to 500 MHz		
	$V_{out} = 0.5 V (V_{pp})$		
	100 MHz signal,	typ. –55 dBc	
	bandwidth 0 MHz to 500 MHz		
	$V_{out} = 0.5 V (V_{pp})$		
	150 MHz signal,	typ. –50 dBc	
	bandwidth 0 MHz to 500 MHz		
	$V_{out} = 0.5 V (V_{pp})$		
Noise floor	at $V_{pp} = 0.7 V$	<–154 dBc (1 Hz)	
Digital filters		4 filters (15 taps each) in butterfly	
-		structure 4	
Skew between I and Q channel		-2 ns to +2 ns	
		(can be digitally set in steps of 10 ps) <sup>4</sup>	
DC offset	alignment	automatic, separately for each channel	
	residual offset	<±1 mV (after auto alignment)	

<sup>&</sup>lt;sup>3</sup> Measured with additional external channel filter.

<sup>&</sup>lt;sup>4</sup> R&S<sup>®</sup>AFQ100A and R&S<sup>®</sup>AFQ100B, mode 1.

### **Operating modes**

Continuous output		repetitive output of waveform from output memory
Single output		single output of waveform from output memory
Segment mode		output of up to 2048 different segments; for each segment, the stepping condition for advancing to the next segment (NEXT) can be selected
Trigger inputs	input level	2, TRIG and NEXT (BNC) 0 V to 3 V, threshold can be set between 10 mV and 1.9 V
	input impedance	50 Ω/1 kΩ, switchable
	pulse width	min. 10 ns
	min. trigger repetition period	100 µs + 25 memory clock cycles
	dead time between trigger input and output of first data word	1.8 μs + 13 memory clock cycles + 3.3 ns jitter; with an external trigger, the output is synchronized with the trigger input
Direct IF		digital modulator for direct generation of user-selectable IF (within signal bandwidth)

### Auxiliary outputs

Markers		user-configurable signals aligned to data words
	number	4, BNC
	level	LVTTL, 2 V into 50 $\Omega$

## BERT (R&S<sup>®</sup>AFQ-K80 option)

instrument. Results are transferred to the Pseudo-random binary sequences	· · · · ·	PRBS9, PRBS11, PRBS15, PRBS16,
		PRBS20, PRBS21, PRBS23
Clock source		clock signal supplied by DUT; one clock pulse is required for each valid bit
Clock rate		min. 1 kHz, max. 100 MHz
Interface		BNC
	data	TTL
	clock	TTL
	setup time	4 ns
	hold time	0 ns
Polarity		normal and inverted (data, clock)
	input level	0 V to 3 V, selectable threshold
	input impedance	50 Ω/1 kΩ, switchable
Results		BER in ppm

# Digital outputs (R&S<sup>®</sup>AFQ-B18 option)

Output	port 1	multiplexed I/Q data stream, compatible with other Rohde & Schwarz equipment
	port 2	parallel I/Q interface
Port 1	operating modes	
	interpolated	memory data with digital lowpass filter and clock rate converter (conversion to interface clock)
	with enable	valid samples are marked with a "data valid" bit in the data stream
	clock source	external, internal
	interface	26-pin I/Q interface
	data	LVDS
	clock	LVDS
Port 2	operating mode	direct output of memory data
	clock source	external, internal
	interface	68-pin HD-SCSI, 16 bit for each I and Q, 2 data clock lines
	data	LVDS, >±200 mV into 100 Ω
	clock	LVDS, >±200 mV into 100 Ω
	skew	200 ps
	rise time	400 ps

### **General data**

Computer	industrial PC
Mass memory	3.5" SATA hard disk drive, 160 Gbyte
Interfaces	USB 2.0 (master and slave), Gigabit
	Ethernet, IEC 625 (IEEE 488)
Operating software updates	via USB
Remote control	via USB, Ethernet, IEC 625-2 (IEEE 488)
Command set	SCPI 1996.0 with extensions
IEC/IEEE interface functions	SH1, AH1, T6, L4, SR1, RL1, PP1, DC1,
	DT1, C0

### **Operating data**

Power supply		100 V to 240 V AC, 50 Hz to 60 Hz,
		2.0 A to 1.0 A
	power factor correction	in line with EN 61000-3-2
	EMC	in line with EN 55011 class B, EN 61326
Electromagnetic compatibility		in line with EN 55011 class B and
		EN 61326
	immunity to RFI	10 V/m
Environmental conditions	operating temperature range	+5 °C to +45 °C;
		in line with IEC 68-2-1 and IEC 68-2-2
	storage temperature range	-40 °C to +70 °C
	climatic stress	
	damp heat	95 % relative humidity at +40 °C;
		in line with IEC 68-2-1, without
		condensation
Mechanical resistance	vibration, sinusoidal	5 Hz to 150 Hz, max. 2 g at 55 Hz,
		max. 0.5 g at 55 Hz to 150 Hz,
		in line with EN 60068-2-6
	vibration, random	10 Hz to 300 Hz, acceleration 1.2 g (rms)
		in line with EN 60068-2-64
	shock	40 g shock spectrum,
		in line with EN 60068-2-27, MIL-STD-810E
Electrical safety		in line with IEC 1010-1, EN 61010-1,
		UL 61010-1, CAN/CSA-C22.2
		No. 61010-1-04
Approvals		VDE-GS, <sub>C</sub> CSA <sub>US</sub>
Dimensions	W×H×D	426.7 mm × 87.6 mm × 450 mm
		(16.80 in × 3.45 in × 17.72 in)
Weight	when fully equipped	7.5 kg
		(16.53 lb)
Recommended calibration interval		3 years

Specifications apply under the following conditions: 30 minutes warm-up time at ambient temperature, specified environmental conditions met, calibration cycle adhered to, and all internal automatic adjustments performed.

"Typical values" are designated with the abbreviation "typ." These values are verified during the final test but are not assured by Rohde & Schwarz. "Nominal values" are design parameters that are not assured by Rohde & Schwarz. These values are verified during product development but are not specifically tested during production.

EMC specifications are tested with sufficiently shielded cables and accessories (e.g. mouse and keypad, double-shielded cables for I and Q, rear BNC connectors). To prevent degradation of these specifications, appropriate equipment must be used.

Rohde & Schwarz equipment is designed for reliable operation up to an altitude of 3000 m above sea level, and for transport up to an altitude of 4600 m above sea level.

## **Ordering information**

Designation	Туре	Order No.
I/Q Modulation Generator <sup>5</sup>	R&S <sup>®</sup> AFQ100A	1401.3003.02
UWB Signal and I/Q Modulation Generator <sup>6</sup>	R&S <sup>®</sup> AFQ100B	1410.9000.02
Including power cable, Quick Start Guide and CD-ROM (with c	operating and service manual	)
Options	· •	
Baseband hardware		
Waveform Memory 256 Msample 7	R&S <sup>®</sup> AFQ-B10	1401.5106.02
Waveform Memory 1 Gsample	R&S <sup>®</sup> AFQ-B11	1401.5206.02
Waveform Memory 512 Msample 8	R&S <sup>®</sup> AFQ-B12	1411.0007.02
Digital I/Q Output	R&S <sup>®</sup> AFQ-B18	1401.5306.02
Baseband software	· ·	
Bit Error Ratio Tester	R&S <sup>®</sup> AFQ-K80	1401.5006.02
Pulse Sequencer	R&S <sup>®</sup> AFQ-K6	1401.5606.02
R&S <sup>®</sup> WinIQSIM2™ options	·	
Digital Standard GSM/EDGE	R&S <sup>®</sup> AFQ-K240	1401.6302.02
Digital Standard 3GPP FDD	R&S <sup>®</sup> AFQ-K242	1401.6354.02
Digital Standard 3GPP FDD Enhanced MS/BS Tests, incl. HSDPA	R&S <sup>®</sup> AFQ-K243	1401.6402.02
Digital Standard GPS	R&S <sup>®</sup> AFQ-K244	1401.6454.02
Digital Standard HSUPA	R&S <sup>®</sup> AFQ-K245	1401.6504.02
Digital Standard CDMA2000 <sup>®</sup> incl. 1xEV-DV	R&S <sup>®</sup> AFQ-K246	1401.6554.02
Digital Standard 1xEV-DO Rev. A	R&S <sup>®</sup> AFQ-K247	1401.5958.02
Digital Standard IEEE 802.11 (a/b/g)	R&S <sup>®</sup> AFQ-K248	1401.6602.02
Digital Standard IEEE 802.16	R&S <sup>®</sup> AFQ-K249	1401.6654.02
Digital Standard TD-SCDMA	R&S <sup>®</sup> AFQ-K250	1401.6702.02
Digital Standard TD-SCDMA Enhanced	R&S <sup>®</sup> AFQ-K251	1401.6754.02
Digital Standard DVB-H	R&S <sup>®</sup> AFQ-K252	1401.5858.02
Digital Standard IEEE 802.11n	R&S <sup>®</sup> AFQ-K254	1401.5806.02
Digital Standard EUTRA	R&S <sup>®</sup> AFQ-K255	1401.5906.02
Digital Standard XM Radio	R&S <sup>®</sup> AFQ-K256	1401.6002.02
Digital Standard HSPA+	R&S <sup>®</sup> AFQ-K259	1401.5658.02
Multicarrier CW Signal Generation	R&S <sup>®</sup> AFQ-K261	1401.6802.02
Additive White Gaussian Noise	R&S <sup>®</sup> AFQ-K262	1401.6854.02
Digital Standard ECMA-368 (UWB) 8	R&S <sup>®</sup> AFQ-K264	1410.8504.02
Recommended extras	· ·	
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